

Notice of References Cited	Application/Control No. 09/433,204	Applicant(s)/Patent Under Reexamination HAMM ET AL.	
	Examiner W. David Coleman	Art Unit 2823	Pag 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5,340,755	08-1994	Zwacknagl et al.	438/312
	B	US-6,310,368	10-2001	Yagura, Motoji	257/197
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Kouhei Morizuka et al., "AlGaAs/GaAs HBT's Fabricated by a Self-Alignment Technology Using Polyimide for Electrode Separation" IEEE, Electron Device Letters, vol. 9, no. 11 November 1998, pp 598-600.
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.